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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/653,925	09/01/2000	Nikhil Vishwanath Kelkar	NSC1P181/P04767	7254

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BEYER WEAVER & THOMAS LLP  
P.O. BOX 778  
BERKELEY, CA 94704-0778

EXAMINER

PAREKH, NITIN

ART UNIT

PAPER NUMBER

2811

DATE MAILED: 09/17/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

<b>Office Action Summary</b>	Application No.	Applicant(s)	
	09/653,925	KELKAR ET AL.	
	Examiner	Art Unit	
	Nitin Parekh	2811	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

**Period of Reply**

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

**Status**

- 1) ☒ Responsive to communication(s) filed on 07 July 2003.
- 2a) ☒ This action is **FINAL**.                      2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

**Disposition of Claims**

- 4) ☒ Claim(s) 1-3, 5-7, 15-17, 19-22, 25, 26 and 29-34 is/are pending in the application.
- 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.
- 5) ☐ Claim(s) \_\_\_\_\_ is/are allowed.
- 6) ☒ Claim(s) 1-3, 5-7, 15-17, 19-22, 25, 26 and 29-34 is/are rejected.
- 7) ☐ Claim(s) \_\_\_\_\_ is/are objected to.
- 8) ☐ Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

**Application Papers**

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 09-01-2000 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.  
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
- 11) ☐ The proposed drawing correction filed on \_\_\_\_\_ is: a) ☐ approved b) ☐ disapproved by the Examiner.  
If approved, corrected drawings are required in reply to this Office action.
- 12) ☐ The oath or declaration is objected to by the Examiner.

**Priority under 35 U.S.C. §§ 119 and 120**

- 13) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  
a) ☐ All b) ☐ Some \* c) ☐ None of:  
1. ☐ Certified copies of the priority documents have been received.  
2. ☐ Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.  
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  
\* See the attached detailed Office action for a list of the certified copies not received.
- 14) ☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).  
a) ☐ The translation of the foreign language provisional application has been received.
- 15) ☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.

**Attachment(s)**

- |  |   |
|--|---|
| 1) <input type="checkbox"/> Notice of References Cited (PTO-892)                             | 4) <input type="checkbox"/> Interview Summary (PTO-413) Paper No(s). _____  |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Review (PTO-948)                 | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449) Paper No(s) _____ | 6) <input type="checkbox"/> Other: _____                                    |

**DETAILED ACTION**

***Claim Rejections - 35 USC § 103***

1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

2. Claims 1, 2, 5, 6, 21, 22, 29-31 are rejected under 35 U.S.C. 103(a) as being unpatentable over Frankeny et al. (US Pat. 5691041) in view of Ohshima et al. (US Pat. 5936843).

Regarding claim 1, Frankeny et al. disclose an integrated circuit (IC) package comprising:

- an IC die (1 in Fig. 6) having a top side and bottom side opposite to the top side, the top side of the die including raised interconnects/bumps (2 in Fig. 6) located over and conductively coupled to the die
- a solid flexible dielectric circuit film (FDCF)/interposer (3 in Fig. 6; Col. 2, line 30; Col. 5, line 30) having top and bottom surfaces, the FDCF being made of a plurality of layers (Col. 5, line 30) the FDCF having outer landing pads/plated layer and inner landing pads/plated layer being formed on the top/bottom surfaces respectively (not numerically referenced- see pads at locations 11, 12,

13, etc. and over interconnects 2 in Fig. 6; also see pads vias 6/7/8 in Fig. 2-4), the outer and inner landings/pads being fully supported by the circuit film, the outer and inner landings having a configuration such that the outer landing is being laterally offset from the inner landing (not numerically referenced- see outer pad at location 13 being connected to the inner pad under interconnect 2 in Fig. 6) or in alignment with the inner landing (not numerically referenced- see outer pad at location 11, 14, 18, etc. being connected to the inner pad under respective interconnects 2 in Fig. 6)

- the outer and inner landings being connected within the solid FDCF via a plated through-hole conductor (not numerically referenced- see the plated through-hole in Fig. 6; Col. 4, line 29)
- a routing conductor/internal wiring layer (16 in Fig. 6) extending laterally within the solid FDCF to provide the desired ground or power/signal connections (Col. 4, line 63)
- the FDCF being located over and conductively attached to the raised interconnects/bumps such that an air gap is formed between the IC die and the FDCF, the height of the air gap being less than the diameter of solder balls (see Fig. 6), and
- contact bumps/balls (9 in Fig. 6) being conductively coupled with the respective outer landings of the FDCF

(Fig. 6; Col. 4, line 30- Col. 6, line 65; Fig. 2-4).

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Frankeny et al. fail to teach:

a) using at least one bond pad coupling the raised interconnect/bump on the topside of the die, and

b) the outer and inner landings being connected within the solid FDCF via a routing conductor extending laterally within the solid FDCF

a) Ohshima et al. teach using an IC package where conventional bond pads couple the raised interconnect/bumps on a chip/die (74-1 and 82b respectively in Fig. 4; Col. 6, lines 10-50).

b) Ohshima et al. further teach using a thin film/solid multilayered wiring board substrate (MLBS)/dielectric circuit substrate where an outer and inner landings (78a/78b and 76a/76b respectively in Fig. 4) are connected within the MLBS via a routing conductor extending vertically and laterally (see 80a/80b in Fig. 4) within the MLBS (Col. 6, line 1-Col. 8, line 47), the laterally extended segment being required/configured to provide the desired connection having an offset between the inner and outer landings, pitch/density conversion between respective terminals (see distance LC versus LA in Fig. 4), miniaturization of the IC and yield improvement (Col. 6, lines 35-40; Col. 8, lines 1-15).

It would have been obvious to a person of ordinary skill in the art at the time invention was made to incorporate at least one bond pad coupling the raised interconnect/bump on the topside of the die and the outer and inner landings being connected within the solid FDCF via a routing conductor extending laterally within the solid FDCF as taught by Ohshima et al. so that the desired terminal pitch/density conversion between the top and bottom surfaces of the substrate and the miniaturization of the IC can be achieved in Frankeny et al's package.

Regarding claim 2, Frankeny et al. and Ohshima et al. teach substantially the entire claimed structure as applied to claim 1 above, except the height of the air gap being in a range of 10-500 microns.

Frankeny et al. further teach conventional solder balls having diameter of about 125 microns (Col. 2, line 15) providing the height the air gap being in a range of 10-500 microns.

It would have been obvious to a person of ordinary skill in the art at the time invention was made to select the air gap/height being in a range of 10-500 microns so that the overall package size can be reduced and the test repair/inspection can be improved in Ohshima et al. and Frankeny et al's package.

Regarding claim 5, Frankeny et al. and Ohshima et al. teach substantially the entire claimed structure as applied to claim 1 above, except a horizontal offset distance between the outer and inner landings being in a range of 50-1000 microns.

Frankeny et al. further teach using the spacing of conventional solder balls connected on the lands being 250 microns (Col. 2, line 15) such that the horizontal offset distance between the inner and outer landings falls in a range of 50-1000 microns.

It would have been obvious to a person of ordinary skill in the art at the time invention was made to select the horizontal offset distance between the outer and inner landings being in a range of 50-1000 microns so that the desired terminal pitch/density conversion between the top and bottom surfaces of the substrate and the miniaturization of the IC can be achieved in Ohshima et al. and Frankeny et al's package.

Regarding claim 6, Frankeny et al. and Ohshima et al. teach substantially the entire claimed structure as applied to claim 1 above, wherein Frankeny et al. teach the contact bumps (9 in Fig. 6) being conductively coupled with the respective outer landings of the FDCF.



Regarding claim 21, Frankeny et al. and Ohshima et al. teach substantially the entire claimed structure as applied to claim 1 above, wherein Frankeny et al. teach the FDCF being made of multiple layers (Col. 5, line 30).

Regarding claim 22, Frankeny et al. and Ohshima et al. teach substantially the entire claimed structure as applied to claim 1 above, wherein Frankeny et al. teach connecting the outer and inner landings via a routing connector such as a plated through hole (not numerically referenced- see plated through hole connector connecting 2 and 9 at locations on top/bottom surfaces of 3 in Fig. 6; Col. 4, line 42) in such a way as to form a cantilever-like structure.

Regarding claims 29 and 30, Frankeny et al. and Ohshima et al. teach substantially the entire claimed structure as applied to claim 1 above, except the laterally extended segment of the routing conductor is necessarily required to connect the two landings and the routing conductor is formed into a step-like shape respectively.

Ohshima et al. further teach the outer and inner landings (78a/78b and 76a/76b respectively in Fig. 4) being connected within the MLBS via a step-shaped routing conductor extending vertically and laterally (see 80a/80b in Fig. 4) within the MLBS (Col. 6, line 1-Col. 8, line 47) where the laterally extended segment (not numerically referenced- see horizontal segment in Fig. 4) is required/configured to provide the desired connection having an offset between the inner and outer landings, the desired

pitch/density conversion between respective terminals (see distance LC versus LA in Fig. 4), miniaturization of the IC and yield improvement (Col. 6, lines 35-40; Col. 8, lines 1-15). Furthermore, the lateral segment connects a first and second vertical segments (not numerically referenced- see two vertical segment in Fig. 4), which further connect to the outer and inner landings respectively (78b and 76b respectively in Fig. 4) to provide a lateral offset between the two vertical segments.

It would have been obvious to a person of ordinary skill in the art at the time invention was made to incorporate the laterally extended segment of the routing conductor being necessarily required to connect the two landings, the routing conductor having a step-like shape, as taught by Ohshima et al. so that the desired terminal pitch/density conversion between the top and bottom surfaces of the substrate and the miniaturization of the IC can be achieved in Frankeny et al's package.

Regarding claim 31, Frankeny et al. and Ohshima et al. teach substantially the entire claimed structure as applied to claims 1, 29 and 30 above, except the routing conductor connects the outer and inner landings with a first and second vertical segments respectively such that two vertical segments are laterally offset and are necessarily connected together with the laterally extended segment.

Ohshima et al. further teach the outer and inner landings (78a/78b and 76a/76b respectively in Fig. 4) being connected within the MLBS via a step-shaped routing conductor extending vertically and laterally (see 80a/80b in Fig. 4) within the MLBS

(Col. 6, line 1-Col. 8, line 47) where the laterally extended segment (not numerically referenced- see horizontal segment in Fig. 4) is required/configured to provide the desired connection having an offset between the inner and outer landings, the desired pitch/density conversion between respective terminals (see distance LC versus LA in Fig. 4), miniaturization of the IC and yield improvement (Col. 6, lines 35-40; Col. 8, lines 1-15). Furthermore, the lateral segment connects a first and second vertical segments (not numerically referenced- see two vertical segment in Fig. 4), which further connect to the outer and inner landings respectively (78b and 76b respectively in Fig. 4) to provide a lateral offset between the two vertical segments.

It would have been obvious to a person of ordinary skill in the art at the time invention was made to incorporate the routing conductor connects the outer and inner landings with a first and second vertical segments respectively such that two vertical segments are laterally offset and are necessarily connected together with the laterally extended segment as taught by Ohshima et al. so that the desired terminal pitch/density conversion between the top and bottom surfaces of the substrate and the miniaturization of the IC can be achieved in Frankeny et al's package.

3. Claim 3 is rejected under 35 U.S.C. 103(a) as being unpatentable over Frankeny et al. (US Pat. 5691041) and Ohshima et al. (US Pat. 5936843) as applied to claim 1 above, and further in view of Wang et al. (US Pat. 6081026).

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Regarding claim 3, Frankeny et al. and Ohshima et al. teach substantially the entire claimed structure as applied to claim 1 above, except the FDCF being substantially of the same size as the IC die.

Wang et al. teach using an IC package having a flexible dielectric circuit film (FDCF 100 in Fig. 1) where an IC die (104 in Fig. 1) has substantially the same size as the FDCF.

It would have been obvious to a person of ordinary skill in the art at the time invention was made to incorporate the FDCF being substantially of the same size as the IC die as taught by Wang et al. so that the package dimensions can be reduced and the fabrication/processing can be simplified in Ohshima et al. and Frankeny et al's package.

4. Claim 7 is rejected under 35 U.S.C. 103(a) as being unpatentable over Frankeny et al. (US Pat. 5691041) and Ohshima et al. (US Pat. 5936843) as applied to claim 1 above, and further in view of Akagawa et al. (US Pat. 5834844).

Regarding claim 7, Frankeny et al. and Ohshima et al. teach substantially the entire claimed structure as applied to claim 1 above, except an under bump pad being formed over the bond pad and conductively coupling at least one bond pad and one raised interconnect.

Akagawa et al. teach using an IC (32 in Fig. 22) having a variety of conventional configurations of bonding pad/landings and an internal wiring where the under bump

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pads (60 in Fig. 22) are formed over the bonding pad/landing portions and being conductively coupled to the raised interconnects/projection bumps (Fig. 22 and 26-28; Col. 8, line 26-40).

It would have been obvious to a person of ordinary skill in the art at the time invention was made to incorporate an under bump pad being formed over the bond pad and conductively coupling at least one bond pad and one raised interconnect. as taught by Akagawa et al. so that the bond strength and interconnect reliability can be improved in Ohshima et al. and Frankeny et al's package.

5. Claims 15, 16, 19, 20, 25, 26 and 32-34 are rejected under 35 U.S.C. 103(a) as being unpatentable over Frankeny et al. (US Pat. 5691041) in view of Ohshima et al. (US Pat. 5936843) and Mizuno et al. (US Pat. 6077757).

Regarding claim 15, Frankeny et al. disclose an integrated circuit (IC) package comprising:

- an IC die (1 in Fig. 6) having a top side and bottom side opposite to the top side, the top side of the die including raised interconnects/bumps (2 in Fig. 6) located over and conductively coupled to the die
- a solid flexible dielectric circuit film (FDCF)/interposer (3 in Fig. 6; Col. 2, line 30; Col. 5, line 30) having top and bottom surfaces, the FDCF being made of a plurality of layers (Col. 5, line 30) the FDCF having outer landing pads/plated

layer and inner landing pads/plated layer being formed on the top/bottom surfaces respectively (not numerically referenced- see pads at locations 11, 12, 13, etc. and over interconnects 2 in Fig. 6; also see pads vias 6/7/8 in Fig. 2-4), the outer and inner landings/pads being fully supported by the circuit film, the outer and inner landings having a configuration such that the outer landing is being laterally offset from the inner landing (not numerically referenced- see outer pad at location 13 being connected to the inner pad under interconnect 2 in Fig. 6) or in alignment with the inner landing (not numerically referenced- see outer pad at location 11, 14, 18, etc. being connected to the inner pad under respective interconnects 2 in Fig. 6)

- the outer and inner landings being connected within the solid FDCF via a plated through-hole conductor (not numerically referenced- see the plated through-hole in Fig. 6; Col. 4, line 29)
- a routing conductor/internal wiring layer (16 in Fig. 6) extending laterally within the solid FDCF to provide the desired ground or power/signal connections (Col. 4, line 63)
- the FDCF being located over and conductively attached to the raised interconnects/bumps such that an air gap is formed between the IC die and the FDCF, the height of the air gap being less than the diameter of solder balls (see Fig. 6), and

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- contact bumps/balls (9 in Fig. 6) being conductively coupled with the respective outer landings of the FDCF

(Fig. 6; Col. 4, line 30- Col. 6, line 65; Fig. 2-4).

Frankeny et al. fail to teach:

- a) at least one bond pad coupling the raised interconnect/bump on the topside of the die
- b) the outer and inner landings being connected within the solid FDCF via a routing conductor extending laterally within the solid FDCF, and
- c) the IC package having an IC wafer comprising a plurality of IC dice

a) Ohshima et al. teach using an IC package where conventional bond pads couple the raised interconnect/bumps on a chip/die (74-1 and 82b respectively in Fig. 4; Col. 6, lines 10-50).

b) Ohshima et al. further teach using a thin film/solid multilayered wiring board substrate (MLBS)/dielectric circuit substrate where an outer and inner landings (78a/78b and 76a/76b respectively in Fig. 4) are connected within the MLBS via a routing conductor extending vertically and laterally (see 80a/80b in Fig. 4) within the MLBS (Col. 6, line 1-Col. 8, line 47) ), the laterally extended segment being required/configured to provide the desired offset between the inner and outer landings,

pitch/density conversion between respective terminals (see distance LC versus LA in Fig. 4), miniaturization of the IC and yield improvement (Col. 6, lines 35-40; Col. 8, lines 1-15).

c) Mizuno et al. teach forming a conventional wafer scale package (WSP) package using a wafer and an insulating substrate (1 and 5 respectively in Fig. 4A-4F), the wafer comprising a plurality of IC die and being singulated to form a plurality of IC die packages (Col. 3, line 40- Col. 4, line 5, line 10).

It would have been obvious to a person of ordinary skill in the art at the time invention was made to incorporate the elements a) and b) above, as taught by Ohshima et al. and the element c) as taught by Mizuno et al. so that the desired terminal pitch/density, bond strength/reliability and the cycle time can be improved in Frankeny et al's IC package.

Regarding claim 16, Frankeny et al., Ohshima et al. and Mizuno et al. teach substantially the entire claimed structure as applied to claim 15 above, except the height of the air gap being in a range of 10-500 microns.

Frankeny et al. further teach conventional solder balls having diameter of about 125 microns (Col. 2, line 15) providing the height the air gap being in a range of 10-500 microns.



It would have been obvious to a person of ordinary skill in the art at the time invention was made to select the air gap/height being in a range of 10-500 microns so that the overall package size can be reduced and the test repair/inspection can be improved in Mizuno et al., Ohshima et al. and Frankeny et al's package.

Regarding claim 19, Frankeny et al., Ohshima et al. and Mizuno et al. teach substantially the entire claimed structure as applied to claim 15 above, except a horizontal offset distance between the outer and inner landings being in a range of 50-1000 microns.

Frankeny et al. further teach using the spacing of conventional solder balls connected on the lands being 250 microns (Col. 2, line 15) such that the horizontal offset distance between the inner and outer landings falls in a range of 50-1000 microns.

It would have been obvious to a person of ordinary skill in the art at the time invention was made to select the horizontal offset distance between the outer and inner landings being in a range of 50-1000 microns so that the desired terminal pitch/density conversion between the top and bottom surfaces of the substrate and the miniaturization of the IC can be achieved in Mizuno et al., Ohshima et al. and Frankeny et al's package.

Regarding claim 20, Frankeny et al., Ohshima et al. and Mizuno et al. teach substantially the entire claimed structure as applied to claim 15 above, wherein Frankeny et al. teach the contact bumps (9 in Fig. 6) being conductively coupled with the respective outer landings of the FDCF.

Regarding claim 25, Frankeny et al., Ohshima et al. and Mizuno et al. teach substantially the entire claimed structure as applied to claim 15 above, wherein Frankeny et al. teach the FDCF being made of multiple layers (Col. 5, line 30).

Regarding claim 26, Frankeny et al., Ohshima et al. and Mizuno et al. teach substantially the entire claimed structure as applied to claim 15 above, wherein Frankeny et al. teach connecting the outer and inner landings via a routing connector such as a plated through hole (not numerically referenced- see plated through hole connector connecting 2 and 9 at location 13 2 in Fig. 6; Col. 4, line 42) in such a way as to form a cantilever-like structure.

Regarding claims 32 and 33, Frankeny et al., Ohshima et al. and Mizuno et al. teach substantially the entire claimed structure as applied to claim 15 above, except the laterally extended segment of the routing conductor being necessarily required to connect the two landings and the routing conductor being formed into a step-like shape respectively.

Ohshima et al. further teach the outer and inner landings (78a/78b and 76a/76b respectively in Fig. 4) being connected within the MLBS via a step-shaped routing conductor extending vertically and laterally (see 80a/80b in Fig. 4) within the MLBS (Col. 6, line 1-Col. 8, line 47) where the laterally extended segment (not numerically referenced- see horizontal segment in Fig. 4) is required/configured to provide the desired connection having an offset between the inner and outer landings, the desired pitch/density conversion between respective terminals (see distance LC versus LA in Fig. 4), miniaturization of the IC and yield improvement (Col. 6, lines 35-40; Col. 8, lines 1-15). Furthermore, the lateral segment connects a first and second vertical segments (not numerically referenced- see two vertical segment in Fig. 4), which further connect to the outer and inner landings respectively (78b and 76b respectively in Fig. 4) to provide a lateral offset between the two vertical segments.

It would have been obvious to a person of ordinary skill in the art at the time invention was made to incorporate the laterally extended segment of the routing conductor being necessarily required to connect the two landings, the routing conductor having a step-like shape, as taught by Ohshima et al. so that the desired terminal pitch/density conversion between the top and bottom surfaces of the substrate and the miniaturization of the IC can be achieved in Mizuno et al. and Frankeny et al's package.

Regarding claim 34, Frankeny et al., Ohshima et al. and Mizuno et al. teach substantially the entire claimed structure as applied to claims 15, 32 and 33 above, except the routing conductor connects the outer and inner landings with a first and second vertical segments respectively such that two vertical segments are laterally offset and are necessarily connected together with the laterally extended segment.

Ohshima et al. further teach the outer and inner landings (78a/78b and 76a/76b respectively in Fig. 4) being connected within the MLBS via a step-shaped routing conductor extending vertically and laterally (see 80a/80b in Fig. 4) within the MLBS (Col. 6, line 1-Col. 8, line 47) where the laterally extended segment (not numerically referenced- see horizontal segment in Fig. 4) is required/configured to provide the desired connection having an offset between the inner and outer landings, the desired pitch/density conversion between respective terminals (see distance LC versus LA in Fig. 4), miniaturization of the IC and yield improvement (Col. 6, lines 35-40; Col. 8, lines 1-15). Furthermore, the lateral segment connects a first and second vertical segments (not numerically referenced- see two vertical segment in Fig. 4), which further connect to the outer and inner landings respectively (78b and 76b respectively in Fig. 4) to provide a lateral offset between the two vertical segments.

It would have been obvious to a person of ordinary skill in the art at the time invention was made to incorporate the routing conductor connects the outer and inner landings with a first and second vertical segments respectively such that two vertical segments are laterally offset and are necessarily connected together with the laterally

extended segment as taught by Ohshima et al. so that the desired terminal pitch/density conversion between the top and bottom surfaces of the substrate and the miniaturization of the IC can be achieved in Mizuno et al. and Frankeny et al's package.

5. Claim 17 is rejected under 35 U.S.C. 103(a) as being unpatentable over Frankeny et al. (US Pat. 5691041), Ohshima et al. (US Pat. 5936843) and Mizuno et al. (US Pat. 6077757) as applied to claim 15 above, and further in view of Akagawa et al. (US Pat. 5834844).

Regarding claim 17, Frankeny et al., Ohshima et al. and Mizuno et al. teach substantially the entire claimed structure as applied to claim 1 above, except an under bump pad being formed over the bond pad and conductively coupling at least one bond pad and one raised interconnect.

Akagawa et al. teach using an IC (32 in Fig. 22) having a variety of conventional configurations of bonding pad/landings and an internal wiring where the under bump pads (60 in Fig. 22) are formed over the bonding pad/landing portions and being conductively coupled to the raised interconnects/projection bumps (Fig. 22 and 26-28; Col. 8, line 26-40).

It would have been obvious to a person of ordinary skill in the art at the time invention was made to incorporate an under bump pad being formed over the bond pad and conductively coupling at least one bond pad and one raised interconnect.

as taught by Akagawa et al. so that the bond strength and interconnect reliability can be improved in Mizuno et al., Ohshima et al. and Frankeny et al's package.

### ***Response to Arguments***

6. Applicant's arguments with respect to claims 1-3, 5-7, 15-17, 19-22, 25, 26 and 29-34 have been considered but are moot in view of the new ground(s) of rejection.

### ***Conclusion***

7. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire **THREE MONTHS** from the mailing date of this action. In the event a first reply is filed within **TWO MONTHS** of the mailing date of this final action and the advisory action is not mailed until after the end of the **THREE-MONTH** shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than **SIX MONTHS** from the mailing date of this final action.

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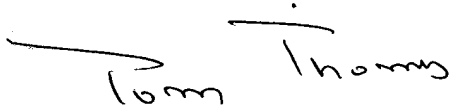
Any inquiry concerning this communication or earlier communications from the examiner should be directed to Nitin Parekh whose telephone number is 703-305-3410. The examiner can normally be reached on 09:00AM-05:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on 703-308-2772. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-306-3431.

Nitin Parekh

09-10-03

  
TOM THOMAS  
SUPERVISORY PATENT EXAMINER  
TECHNOLOGY CENTER 2800